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View Online at https://aerobasegroup.com/nsn/5961-01-392-9045

Inclosure Material:

Ceramic and metal

Overall Length:

1.340 inches

Overall Height:

0.160 inches

Overall Width:

0.800 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Base

Mounting Method:

Slot

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 35.0 collector to emitter voltage/static/base open and 65.0 collector to emitter

voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

109.0 watts any acceptable absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Case contains beryllium oxide - handle and dispose iaw hazmat procedures; junction pattern arrangement: npn

Precious Material And Location:

Internal wire and metalized die and wire bond gold

Precious Material:

Gold

Test Data Document:

13499-352-1550 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

1 case and 4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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